



B320 Thru B360

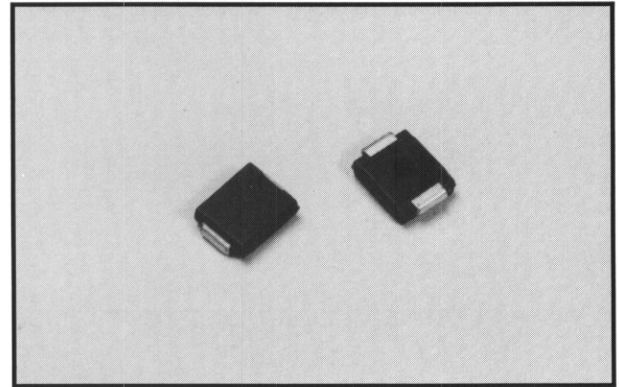
3 AMP SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

FEATURES

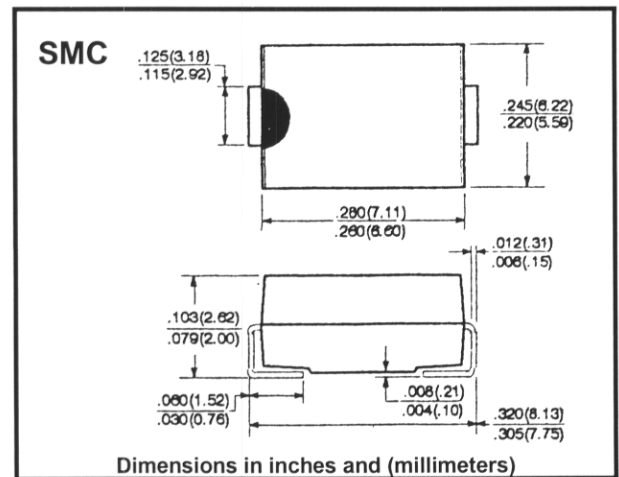
- For surface mount applications
- Metal semiconductor junction with guard ring
- Epitaxial construction
- Low forward voltage drop
- UL recognized 94V-O plastic material
- Lead solderable per MIL-STD-202 Method 208
- Surge overload rating to 100A peak

Mechanical Data

- Case: Molded plastic
- Polarity: Indicated on cathode
- Weight: 0.007 ounces, 0.21 grams



Outline Drawing



Maximum Ratings & Characteristics

- Ratings at 25° C ambient temperature unless otherwise specified
- Single phase, half wave, 60Hz, resistive or inductive load
- For capacitive load, derate current by 20%

| | | B320 | B330 | B340 | B350 | B360 | Units |
|--|---------------------|-------------|------|------|------|------|-------|
| Maximum Recurrent Peak Reverse Voltage | V _{RRM} | 20 | 30 | 40 | 50 | 60 | V |
| Maximum RMS Input Voltage | V _{RMS} | 14 | 21 | 28 | 35 | 42 | V |
| Maximum DC Blocking Voltage | V _{DC} | 20 | 30 | 40 | 50 | 60 | V |
| Maximum Average Forward Output Current .375" 9.5mm lead length @ T _L = 110°C | I (AV) | 3.0 | | | | | A |
| Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave Superimposed On Rated Load | I _{FSM} | 100 | | | | | A |
| Maximum Forward Voltage Drop At 3.0A | V _F | 0.50 | | | 0.70 | | V |
| Maximum Reverse Current At Rated DC Blocking Voltage per Bridge Element @ T _A = 25°C | I _R | 0.5 | | | | | mA |
| | | 20 | | | | | mA |
| Typical Junction Capacitance* (See Note) | C _J | 300 | | | | | pF |
| Typical Thermal Resistance** (See Note) | R _(THJL) | 10 | | | | | °C/W |
| Maximum Thermal Resistance** (See Note) | R _(THJA) | 50 | | | | | °C/W |
| Operating Temperature Range | T _J | -65 to +125 | | | | | °C |
| Storage Temperature Range | T _{STG} | -65 to +150 | | | | | °C |

Note: *Measured at 1.0 MHz and applied reverse voltage of 4.0V DC

**Thermal resistance junction to lead/ambient measured on PC board 8mm² X (0.013mm thick)